## MC10EL35，MC100EL35

## 5 V ECL JK Flip－Flop

## Description

The MC10EL／100EL35 is a high speed JK flip－flop．The J／K data enters the master portion of the flip－flop when the clock is LOW and is transferred to the slave，and thus the outputs，upon a positive transition of the clock．The reset pin is asynchronous and is activated with a logic HIGH．

The 100 Series contains temperature compensation．

## Features

－ 525 ps Propagation Delay
－ 2.2 G Hz Toggle Frequency
－ESD Protection：
－＞ 1 kV Human Body Model
－＞ 100 V Machine Model
－PECL Mode Operating Range： $\mathrm{V}_{\mathrm{CC}}=4.2 \mathrm{~V}$ to 5.7 with $\mathrm{V}_{\mathrm{EE}}=0 \mathrm{~V}$
－NECL Mode Operating Range： $\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}$ with
$\mathrm{V}_{\mathrm{EE}}=-4.2 \mathrm{~V}$ to -5.7 V
－Internal Input Pulldown Resistors on J，K，CLK，and R
－Meets or Exceeds JEDEC Spec EIA／JESD78 IC Latchup Test
－Moisture Sensitivity：
－Level 1 for SOIC－8 NB
－Level 3 for TSSOP－8
－For Additional Information，see Application Note AND8003／D
－Flammability Rating：UL－94 V－0＠ 0.125 in，
Oxygen Index 28 to 34
－Transistor Count $=81$ Devices
－These Devices are Pb－Free，Halogen Free and are RoHS Compliant

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MARKING DIAGRAMS＊


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ALYW：
O．
${ }^{1}$ 膭睤


SOIC－8
TSSOP－8
H＝MC10
$K=$ MC100
A＝Assembly Location
L＝Wafer Lot
Y＝Year
W＝Work Week
－＝Pb－Free Package
（Note：Microdot may be in either location）
＊For additional marking information，refer to Application Note AND8002／D．

ORDERING INFORMATION

| Device | Package | Shipping |
| :--- | :---: | :---: |
| MC10EL35DG | SOIC－8 NB <br> （Pb－Free） | 98 Units／Tube |
| MC10EL35DTG | TSSOP－8 <br> （Pb－Free） | 100 Unit／Tube |
| MC100EL35DG | SOIC－8 NB <br> （Pb－Free） | 98 Units／tube |
| MC100EL35DTG | TSSOP－8 <br> （Pb－Free） | 100 Units／Tube |



Figure 1. Logic Diagram and Pinout Assignment

Table 1. PIN DESCRIPTION

| PIN | FUNCTION |
| :--- | :--- |
| $J$ | ECL Input |
| $K$ | ECL Input |
| $R$ | ECL Reset |
| CLK | ECL Clock Input |
| $Q, \bar{Q}$ | ECL Data Outputs |
| $V_{\text {CC }}$ | Positive Supply |
| $\mathrm{V}_{\mathrm{EE}}$ | Negative Supply |

Table 1. TRUTH TABLE

| $\mathbf{J}^{*}$ | K $^{*}$ | $\mathbf{R}^{\star}$ | CLK | Qn+1 |
| :---: | :---: | :---: | :---: | :---: |
| L | L | L | Z | Qn |
| L | H | L | Z | L |
| H | L | L | Z | H |
| H | H | L | Z | Qn |
| X | X | H | X | L |

Table 2. MAXIMUM RATINGS

| Symbol | Parameter | Condition 1 | Condition 2 | Rating | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | PECL Mode Power Supply | $\mathrm{V}_{\mathrm{EE}}=0 \mathrm{~V}$ |  | 8 | V |
| $\mathrm{V}_{\mathrm{EE}}$ | NECL Mode Power Supply | $\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}$ |  | -8 | V |
| $\mathrm{V}_{1}$ | PECL Mode Input Voltage NECL Mode Input Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{EE}}=0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~V}_{\mathrm{I}} \geq \mathrm{V}_{\mathrm{EE}} \end{aligned}$ | $\begin{gathered} 6 \\ -6 \end{gathered}$ | V |
| $\mathrm{I}_{\text {out }}$ | Output Current | Continuous Surge |  | $\begin{gathered} 50 \\ 100 \end{gathered}$ | mA |
| $\mathrm{T}_{\mathrm{A}}$ | Operating Temperature Range |  |  | -40 to +85 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ | Storage Temperature Range |  |  | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| $\theta_{J A}$ | Thermal Resistance (Junction-to-Ambient) | 0 lfpm 500 lfpm | $\begin{aligned} & \hline \text { SOIC-8 NB } \\ & \text { SOIC-8 NB } \end{aligned}$ | $\begin{aligned} & 190 \\ & 130 \end{aligned}$ | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\theta_{\mathrm{Jc}}$ | Thermal Resistance (Junction-to-Case) | Standard Board | SOIC-8 NB | 41 to 44 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\theta_{J A}$ | Thermal Resistance (Junction-to-Ambient) | 0 lfpm 500 lfpm | $\begin{aligned} & \text { TSSOP-8 } \\ & \text { TSSOP-8 } \end{aligned}$ | $\begin{aligned} & 185 \\ & 140 \end{aligned}$ | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\theta_{\text {JC }}$ | Thermal Resistance (Junction-to-Case) | Standard Board | TSSOP-8 | 41 to $44 \pm 5 \%$ | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{T}_{\text {sol }}$ | Wave Solder (Pb-Free) | < 2 to $3 \mathrm{sec} @ 260^{\circ} \mathrm{C}$ |  | 265 | ${ }^{\circ} \mathrm{C}$ |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 3. 10EL SERIES PECL DC CHARACTERISTICS $\left(\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} ; \mathrm{V}_{\mathrm{EE}}=0 \mathrm{~V}\right.$ (Note 1))

| Symbol | Characteristic | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max |  |
| $l_{\text {EE }}$ | Power Supply Current |  | 27 | 32 |  | 27 | 32 |  | 27 | 32 | mA |
| $\mathrm{V}_{\mathrm{OH}}$ | Output HIGH Voltage (Note 2) | 3920 | 4010 | 4110 | 4020 | 4105 | 4190 | 4090 | 4185 | 4280 | mV |
| $\mathrm{V}_{\text {OL }}$ | Output LOW Voltage (Note 2) | 3050 | 3200 | 3350 | 3050 | 3210 | 3370 | 3050 | 3227 | 3405 | mV |
| $\mathrm{V}_{\mathrm{IH}}$ | Input HIGH Voltage | 3770 |  | 4110 | 3870 |  | 4190 | 3940 |  | 4280 | mV |
| $\mathrm{V}_{\text {IL }}$ | Input LOW Voltage | 3050 |  | 3500 | 3050 |  | 3520 | 3050 |  | 3555 | mV |
| $\mathrm{IIH}^{\text {I }}$ | Input HIGH Current |  |  | 150 |  |  | 150 |  |  | 150 | $\mu \mathrm{A}$ |
| IIL | Input LOW Current | 0.5 |  |  | 0.5 |  |  | 0.3 |  |  | $\mu \mathrm{A}$ |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Input and output parameters vary $1: 1$ with $\mathrm{V}_{\mathrm{CC}}$. $\mathrm{V}_{\mathrm{EE}}$ can vary $+0.25 \mathrm{~V} /-0.5 \mathrm{~V}$.
2. Outputs are terminated through a $50 \Omega$ resistor to $\mathrm{V}_{\mathrm{CC}}-2.0 \mathrm{~V}$.

Table 4. 10EL SERIES NECL DC CHARACTERISTICS $\left(\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V} ; \mathrm{V}_{\mathrm{EE}}=-5.0 \mathrm{~V}\right.$ (Note 1))

| Symbol | Characteristic | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max |  |
| $\mathrm{I}_{\text {EE }}$ | Power Supply Current |  | 27 | 32 |  | 27 | 32 |  | 27 | 32 | mA |
| $\mathrm{V}_{\mathrm{OH}}$ | Output HIGH Voltage (Note 2) | -1080 | -990 | -890 | -980 | -895 | -810 | -910 | -815 | -720 | mV |
| $\mathrm{V}_{\text {OL }}$ | Output LOW Voltage (Note 2) | -1950 | -1800 | -1650 | -1950 | -1790 | -1630 | -1950 | -1773 | -1595 | mV |
| $\mathrm{V}_{\mathrm{IH}}$ | Input HIGH Voltage | -1230 |  | -890 | -1130 |  | -810 | -1060 |  | -720 | mV |
| $\mathrm{V}_{\mathrm{IL}}$ | Input LOW Voltage | -1950 |  | -1500 | -1950 |  | -1480 | -1950 |  | -1445 | mV |
| $\mathrm{IIH}^{\text {I }}$ | Input HIGH Current |  |  | 150 |  |  | 150 |  |  | 150 | $\mu \mathrm{A}$ |
| ILL | Input LOW Current | 0.5 |  |  | 0.5 |  |  | 0.3 |  |  | $\mu \mathrm{A}$ |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 Ifpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Input and output parameters vary $1: 1$ with $\mathrm{V}_{\mathrm{CC}} . \mathrm{V}_{\mathrm{EE}}$ can vary $+0.25 \mathrm{~V} /-0.5 \mathrm{~V}$.
2. Outputs are terminated through a $50 \Omega$ resistor to $\mathrm{V}_{\mathrm{CC}}-2.0 \mathrm{~V}$.

Table 5. 100EL SERIES PECL DC CHARACTERISTICS (VCC $=5.0 \mathrm{~V} ; \mathrm{V}_{\mathrm{EE}}=0 \mathrm{~V}$ (Note 1))

| Symbol | Characteristic | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max |  |
| $\mathrm{I}_{\text {EE }}$ | Power Supply Current |  | 27 | 32 |  | 27 | 32 |  | 32 | 37 | mA |
| $\mathrm{V}_{\mathrm{OH}}$ | Output HIGH Voltage (Note 2) | 3915 | 3995 | 4120 | 3975 | 4045 | 4120 | 3975 | 4050 | 4120 | mV |
| $\mathrm{V}_{\text {OL }}$ | Output LOW Voltage (Note 2) | 3170 | 3305 | 3445 | 3190 | 3295 | 3380 | 3190 | 3295 | 3380 | mV |
| $\mathrm{V}_{\mathrm{IH}}$ | Input HIGH Voltage (Single-Ended) | 3835 |  | 4120 | 3835 |  | 4120 | 3835 |  | 4120 | mV |
| $\mathrm{V}_{\mathrm{IL}}$ | Input LOW Voltage (Single-Ended) | 3190 |  | 3525 | 3190 |  | 3525 | 3190 |  | 3525 | mV |
| IIH | Input HIGH Current |  |  | 150 |  |  | 150 |  |  | 150 | $\mu \mathrm{A}$ |
| IIL | Input LOW Current | 0.5 |  |  | 0.5 |  |  | 0.5 |  |  | $\mu \mathrm{A}$ |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 Ifpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Input and output parameters vary $1: 1$ with $\mathrm{V}_{\mathrm{CC}}$. $\mathrm{V}_{\mathrm{EE}}$ can vary $+0.8 \mathrm{~V} /-0.5 \mathrm{~V}$.
2. Outputs are terminated through a $50 \Omega$ resistor to $\mathrm{V}_{\mathrm{CC}}-2.0 \mathrm{~V}$.

Table 6. 100EL SERIES NECL DC CHARACTERISTICS ( $\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}$; $\mathrm{V}_{\mathrm{EE}}=-5.0 \mathrm{~V}$ (Note 1))

| Symbol | Characteristic | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max |  |
| $\mathrm{I}_{\text {EE }}$ | Power Supply Current |  | 27 | 32 |  | 27 | 32 |  | 32 | 37 | mA |
| $\mathrm{V}_{\mathrm{OH}}$ | Output HIGH Voltage (Note 2) | -1085 | -1005 | -880 | -1025 | -955 | -880 | -1025 | -955 | -880 | mV |
| $\mathrm{V}_{\text {OL }}$ | Output LOW Voltage (Note 2) | -1830 | -1695 | -1555 | -1810 | -1705 | -1620 | -1810 | -1705 | -1620 | mV |
| $\mathrm{V}_{\mathrm{IH}}$ | Input HIGH Voltage (Single-Ended) | -1165 |  | -880 | -1165 |  | -880 | -1165 |  | -880 | mV |
| $\mathrm{V}_{\text {IL }}$ | Input LOW Voltage (Single-Ended) | -1810 |  | -1475 | -1810 |  | -1475 | -1810 |  | -1475 | mV |
| $\mathrm{IIH}^{\text {I }}$ | Input HIGH Current |  |  | 150 |  |  | 150 |  |  | 150 | $\mu \mathrm{A}$ |
| IIL | Input LOW Current | 0.5 |  |  | 0.5 |  |  | 0.5 |  |  | $\mu \mathrm{A}$ |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Input and output parameters vary $1: 1$ with $\mathrm{V}_{\mathrm{CC}}$. $\mathrm{V}_{\mathrm{EE}}$ can vary $+0.8 \mathrm{~V} /-0.5 \mathrm{~V}$.
2. Outputs are terminated through a $50 \Omega$ resistor to $\mathrm{V}_{\mathrm{CC}}-2.0 \mathrm{~V}$.-

Table 7. AC CHARACTERISTICS $\left(\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} ; \mathrm{V}_{\mathrm{EE}}=0 \mathrm{~V}\right.$ or $\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V} ; \mathrm{V}_{\mathrm{EE}}=-5.0 \mathrm{~V}$ (Note 1))

| Symbol | Characteristic | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max |  |
| fmax | Maximum Toggle Frequency | 1.4 | 2.0 |  | 1.8 | 2.2 |  | 1.8 | 2.2 |  | GHz |
| $\begin{aligned} & \mathrm{t}_{\mathrm{PLH}} \\ & \mathrm{t}_{\mathrm{PHL}} \end{aligned}$ | Propagation Delay CLK <br> to Output MR | $\begin{aligned} & 290 \\ & 225 \end{aligned}$ | $\begin{aligned} & 515 \\ & 450 \end{aligned}$ | $\begin{aligned} & 740 \\ & 675 \end{aligned}$ | $\begin{aligned} & 350 \\ & 275 \end{aligned}$ | $\begin{aligned} & 525 \\ & 450 \end{aligned}$ | $\begin{aligned} & 700 \\ & 625 \end{aligned}$ | $\begin{aligned} & 395 \\ & 350 \end{aligned}$ | $\begin{aligned} & 570 \\ & 525 \end{aligned}$ | $\begin{aligned} & 745 \\ & 700 \end{aligned}$ | ps |
| $\mathrm{t}_{\mathrm{s}}$ | Setup Time J, K | 150 | 0 |  | 150 | 0 |  | 150 | 0 |  | ps |
| $\mathrm{t}_{\mathrm{H}}$ | Hold Time J, K | 250 | 100 |  | 250 | 100 |  | 250 | 100 |  | ps |
| $t_{\text {RR }}$ | Reset Recovery | 400 | 200 |  | 400 | 200 |  | 400 | 200 |  | ps |
| $t_{\text {PW }}$ | Minimum Pulse Width CLK, Reset | 400 |  |  | 400 |  |  | 400 |  |  | ps |
| $\mathrm{t}_{\text {JITTER }}$ | Cycle-to-Cycle Jitter |  | 1.0 |  |  | 1.0 |  |  | 1.0 |  | ps |
| $t_{r}$ $t_{f}$ | Output Rise/Fall Times Q (20\%-80\%) | 100 | 225 | 350 | 100 | 225 | 350 | 100 | 225 | 350 | ps |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm . Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. 10 Series: $\mathrm{V}_{\mathrm{EE}}$ can vary $+0.25 \mathrm{~V} /-0.5 \mathrm{~V}$.

100 Series: VEE can vary +0.8 V / -0.5 V.

## MC10EL35, MC100EL35



Figure 2. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020/D - Termination of ECL Logic Devices)

## Resource Reference of Application Notes

AN1405/D - ECL Clock Distribution Techniques
AN1406/D - Designing with PECL (ECL at +5.0 V )
AN1503/D - ECLinPS ${ }^{\text {m }}$ I/O SPiCE Modeling Kit
AN1504/D - Metastability and the ECLinPS Family
AN1568/D - Interfacing Between LVDS and ECL
AN1672/D - The ECL Translator Guide
AND8001/D - Odd Number Counters Design
AND8002/D - Marking and Date Codes
AND8020/D - Termination of ECL Logic Devices
AND8066/D - Interfacing with ECLinPS
AND8090/D - AC Characteristics of ECL Devices

## MC10EL35, MC100EL35

## PACKAGE DIMENSIONS

SOIC-8 NB
D SUFFIX CASE 751-07
ISSUE AK


NOTES:
. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR
PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW 751-01 THRU 751-06
STANDARD IS 751-07.

|  | MILLIMETERS |  | INCHES |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DIM | MIN | MAX | MIN | MAX |  |  |
| A | 4.80 | 5.00 | 0.189 | 0.197 |  |  |
| B | 3.80 | 4.00 | 0.150 | 0.157 |  |  |
| $\mathbf{C}$ | 1.35 | 1.75 | 0.053 | 0.069 |  |  |
| $\mathbf{D}$ | 0.33 | 0.51 | 0.013 | 0.020 |  |  |
| G | 1.27 |  | BSC | 0.050 |  | BSC |
| H | 0.10 | 0.25 | 0.004 | 0.010 |  |  |
| $\mathbf{J}$ | 0.19 | 0.25 | 0.007 | 0.010 |  |  |
| $\mathbf{K}$ | 0.40 | 1.27 | 0.016 | 0.050 |  |  |
| $\mathbf{M}$ | 0 | $\circ$ | $8{ }^{\circ}$ | 0 |  |  |
|  | 8 | 8 |  |  |  |  |
| $\mathbf{N}$ | 0.25 | 0.50 | 0.010 | 0.020 |  |  |
| $\mathbf{S}$ | 5.80 | 6.20 | 0.228 | 0.244 |  |  |

## SOLDERING FOOTPRINT*


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## MC10EL35, MC100EL35

## PACKAGE DIMENSIONS

TSSOP-8
DT SUFFIX
CASE 948R-02
ISSUE A


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANS Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-

| DIM | MILLIMETERS |  | INCHES |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |  |  |
| A | 2.90 | 3.10 | 0.114 | 0.122 |  |  |
| B | 2.90 | 3.10 | 0.114 | 0.122 |  |  |
| C | 0.80 | 1.10 | 0.031 | 0.043 |  |  |
| D | 0.05 | 0.15 | 0.002 | 0.006 |  |  |
| F | 0.40 | 0.70 | 0.016 | 0.028 |  |  |
| G | 0.65 BSC |  | 0.026 |  |  |  |
| BSC |  |  |  |  |  |  |
| K | 0.25 |  | 0.40 | 0.010 |  | 0.016 |
| L | 4.90 BSC |  | 0.193 BSC |  |  |  |
| M | $0^{\circ}$ |  | $6^{\circ}$ | $0^{\circ}$ |  | $6^{\circ}$ |

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